

Trans IGBT Chip N-CH 600V 35A 125mW 3-Pin(3+Tab) TO-220AB Tube



Images are for reference only

[Inquiry](#)

Manufacturer: [STMicroelectronics, Inc](#)

Package/Case: TO-220

Product Type: Thyristors

Lifecycle: Active

General Description

These devices are very fast IGBTs developed using advanced PowerMESH™ technology. This process guarantees an excellent trade-off between switching performance and low on-state behavior.

Key Features

Low on voltage drop (VCE(sat))

Low CRES / CIES ratio (no cross-conduction susceptibility)

Short-circuit withstand time 10 μs

IGBT co-packaged with ultrafast free-wheeling diode

Recommended For You

STGIF5CH60TS-L

STMicroelectronics, Inc

SDIP2B-26

STGIPS10K60A

STMicroelectronics, Inc

SDIP-25L

STP24NF10

STMicroelectronics, Inc

TO-220

STGW30NC120HD

STMicroelectronics, Inc

TO-247

STGIPS20K60

STMicroelectronics, Inc

SDIP-25

STB75NF75LT4

STMicroelectronics, Inc

TO-263

STD20NF06LT4

STMicroelectronics, Inc

TO-252

STGW45HF60WD

STMicroelectronics, Inc

TO-247

STGW19NC60HD

STMicroelectronics, Inc

TO-247

STGW30NC60WD

STMicroelectronics, Inc

TO-247

STGW40HI20DF2

STMicroelectronics, Inc

TO-247

STGW40V60DF

STMicroelectronics, Inc

TO-247

STGB10NC60HD

STMicroelectronics, Inc

D2PAK

STGB30V60DF

STMicroelectronics, Inc

TO-263

STGP30H60DF

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TO-220